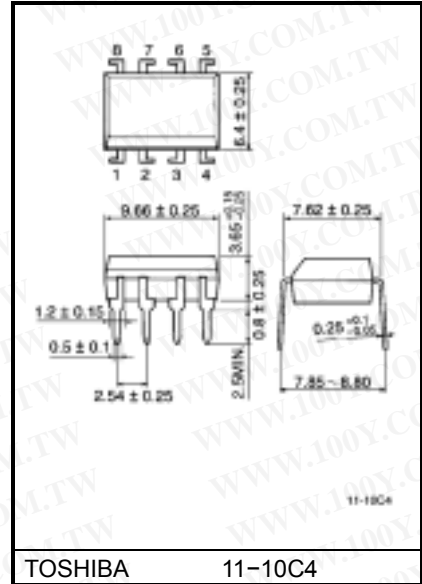


TOSHIBA Photocoupler GaAlAs Ired & Photo-IC

TLP251

- Inverter For Air Conditionor
- Induction Heating
- Transistor Inverter
- Power MOS FET Gate Drive
- IGBT Gate Drive

Unit in mm

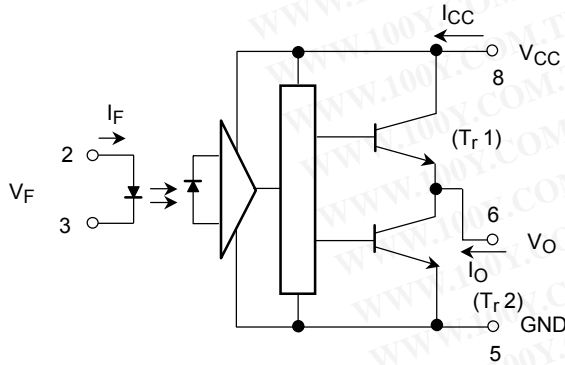


Weight: 0.54g

The TOSHIBA TLP251 consists of a GaAlAs light emitting diode and a integrated photodetector.
 This unit is 8-lead DIP package.
 TLP251 is suitable for gate driving circuit of IGBT or power MOS FET.
 Especially TLP251 is capable of "direct" gate drive of lower power IGBTs.
 (~15A)

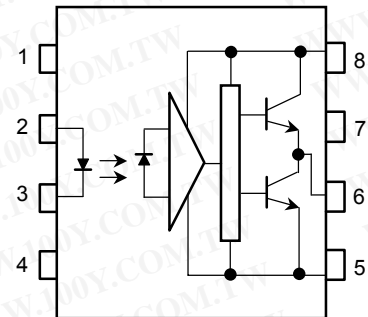
- Input threshold current: $I_F=5\text{mA}(\text{max.})$
- Supply current (I_{CC}): $11\text{mA}(\text{max.})$
- Supply voltage (V_{CC}): $10\text{--}35\text{V}$
- Output current (I_O): $\pm 0.4\text{A}(\text{max.})$
- Switching time (t_{pLH} / t_{pHL}): $1\mu\text{s}(\text{max.})$
- Isolation voltage: $2500\text{Vrms}(\text{min.})$
- UL recognized: UL1577, file no.E67349

Schematic



A 0.1 μF bypass capacitor must be connected between pin 8 and 5(see Note 5).

Pin Configuration (top view)



- 1 : N.C.
- 2 : Anode
- 3 : Cathode
- 4 : N.C.
- 5 : Gnd
- 6 : V_O (Output)
- 7 : N.C.
- 8 : V_{CC}

Truth Table

		Tr1	Tr2
Input LED	On	On	Off
	Off	Off	On

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Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
LED	Forward current	I_F	20	mA	
	Forward current derating (Ta ≥ 70°C)	$\Delta I_F / \Delta T_a$	-0.36	mA / °C	
	Peak transient forward current (Note 1)	I_{FPT}	1	A	
	Reverse voltage	V_R	5	V	
	Junction temperature	T_j	125	°C	
Detector	"H" peak output current ($P_W \leq 2.0\mu s$, $f \leq 15kHz$) (Note 2)	I_{OPH}	-0.4	A	
	"L" peak output current ($P_W \leq 2.0\mu s$, $f \leq 15kHz$) (Note 2)	I_{OPL}	0.4	A	
	Output voltage	(Ta ≤ 70°C)	V_O	35	V
		(Ta = 85°C)		24	
	Supply voltage	(Ta ≤ 70°C)	V_{CC}	35	V
		(Ta = 85°C)		24	
	Output voltage derating (Ta ≥ 70°C)		$\Delta V_O / \Delta T_a$	-0.73	V / °C
	Supply voltage derating (Ta ≥ 70°C)		$\Delta V_{CC} / \Delta T_a$	-0.73	V / °C
	Junction temperature		T_j	125	°C
	Operating frequency (Note 3)		f	25	kHz
Operating temperature range		T_{opr}	-20~85	°C	
Storage temperature range		T_{stg}	-55~125	°C	
Lead soldering temperature(10s) (Note 4)		T_{sol}	260	°C	
Isolation voltage (AC, 1min., R.H. ≤ 60%) (Note 5)		BV_S	2500	Vrms	

Note 1: Pulse width $P_W \leq 1\mu s$, 300pps

Note 2: Exponential waveform

Note 3: Exponential waveform, $I_{OPH} \leq -0.25A (\leq 2.0\mu s)$, $I_{OPL} \leq +0.25A (\leq 2.0\mu s)$

Note 4: It is 2 mm or more from a lead root.

Note 5: Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together, and pins 5, 6, 7 and 8 shorted together.

Note 6: A ceramic capacitor(0.1μF)should be connected from pin 8 to pin 5 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property.The total lead length between capacitor and coupler should not exceed 1cm.

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Recommended Operating Conditions

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Input current, on (Note 7)	$I_{F(ON)}$	7	8	10	mA
Input voltage, off	$V_{F(OFF)}$	0	—	0.8	V
Supply voltage	V_{CC}	10	—	30 20	V
Peak output current	I_{OPH} / I_{OPL}	—	—	±0.1	A
Operating temperature	T_{opr}	-20	25	70 85	°C

Note 7: Input signal rise time (fall time) < 0.5 μs.

Electrical Characteristics (Ta = -20~70°C, unless otherwise specified)

Characteristic	Symbol	Test Circuit	Test Condition	Min.	Typ.*	Max.	Unit		
Input forward voltage	V_F	—	$I_F = 10 \text{ mA}$, $T_a = 25^\circ\text{C}$	—	1.6	1.8	V		
Temperature coefficient of forward voltage	$\Delta V_F / \Delta T_a$	—	$I_F = 10 \text{ mA}$	—	-2.0	—	mV / °C		
Input reverse current	I_R	—	$V_R = 5 \text{ V}$, $T_a = 25^\circ\text{C}$	—	—	10	μA		
Input capacitance	C_T	—	$V = 0$, $f = 1 \text{ MHz}$, $T_a = 25^\circ\text{C}$	—	45	250	pF		
Output current	"H" level	I_{OPH}	3	$V_{CC} = 30 \text{ V}$ (*1)	$I_F = 10 \text{ mA}$ $V_{8-6} = 4 \text{ V}$	-0.1	-0.25	—	A
	"L" level	I_{OPL}	2		$I_F = 0$ $V_{6-5} = 2.5 \text{ V}$	0.1	0.2	—	
Output voltage	"H" level	V_{OH}	4	$V_{CC1} = +15 \text{ V}$, $V_{EE1} = -15 \text{ V}$ $R_L = 200 \Omega$, $I_F = 5 \text{ mA}$	11	13.2	—	V	
	"L" level	V_{OL}	5		$V_{CC1} = +15 \text{ V}$, $V_{EE1} = -15 \text{ V}$ $R_L = 200 \Omega$, $V_F = 0.8 \text{ V}$	—	-14.5		-12.5
Supply current	"H" level	I_{CCH}	—	$V_{CC} = 30 \text{ V}$, $I_F = 10 \text{ mA}$ $T_a = 25^\circ\text{C}$	—	7.5	—	mA	
					—	—	11		
	"L" level	I_{CCL}	—		$V_{CC} = 30 \text{ V}$, $I_F = 0 \text{ mA}$ $T_a = 25^\circ\text{C}$	—	8		—
Threshold input current	"Output L → H"	I_{FLH}	—	$V_{CC1} = +15 \text{ V}$, $V_{EE1} = -15 \text{ V}$ $R_L = 200 \Omega$, $V_O > 0 \text{ V}$	—	1.2	5	mA	
					—	—	—		
Threshold input voltage	"Output H → L"	V_{FLH}	—	$V_{CC1} = +15 \text{ V}$, $V_{EE1} = -15 \text{ V}$ $R_L = 200 \Omega$, $V_O < 0 \text{ V}$	0.8	—	—	V	
Supply voltage	V_{CC}	—	—	10	—	35	V		
Capacitance (input-output)	C_s	—	$V_s = 0$, $f = 1 \text{ MHz}$ $T_a = 25$	—	1.0	2.0	pF		
Resistance (input-output)	R_s	—	$V_s = 500 \text{ V}$, $T_a = 25$ $R.H. \leq 60\%$	1×10^{12}	10^{14}	—	Ω		

* All typical values are at $T_a = 25^\circ\text{C}$ (*1): Duration of I_O time $\leq 50 \mu\text{s}$

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Switching Characteristics (Ta = -20~70°C, unless otherwise specified)

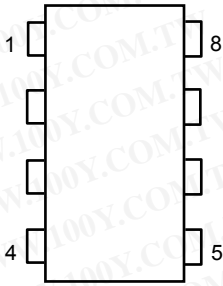
Characteristic		Symbol	Test Cir-cuit	Test Condition	Min.	Typ.*	Max.	Unit
Propagation delay time	L→H	t _{pLH}	6	I _F = 8mA (Note 7) V _{CC1} = +15V, V _{EE1} = -15V R _L = 200 Ω	—	0.25	1.0	μs
	H→L	t _{pHL}			—	0.25	1.0	
Output rise time		t _r			—	—	—	
Output fall time		t _f			—	—	—	
Common mode transient immunity at high level output		C _{MH}	7	V _{CM} = 600V, I _F = 8mA, V _{CC} = 30V, Ta = 25	-5000	—	—	V / μs
Common mode transient immunity at low level output		C _{ML}	7	V _{CM} = 600V, I _F = 0mA, V _{CC} = 30V, Ta = 25	5000	—	—	V / μs

*All typical values are at Ta=25

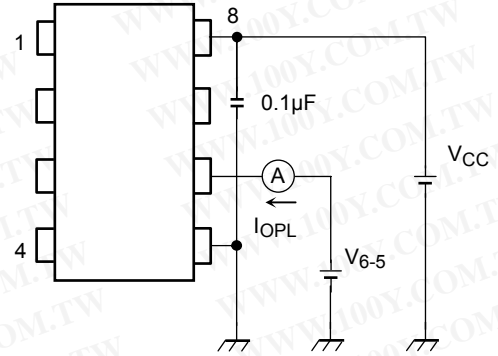
Note 7: Input signal rise time (fall time) < 0.5 μs.

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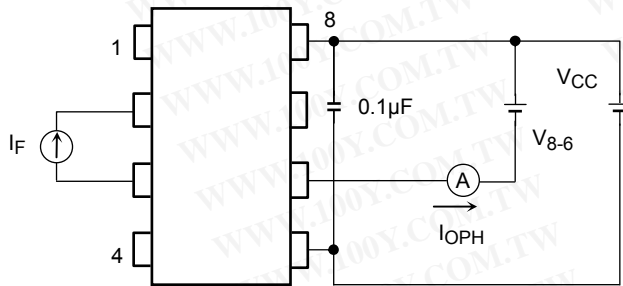
Test Circuit 1:



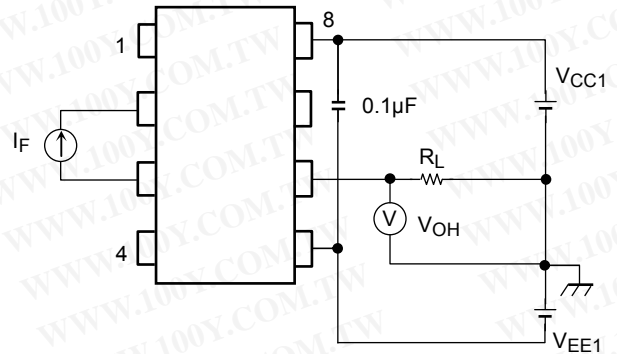
Test Circuit 2: I_{OPL}



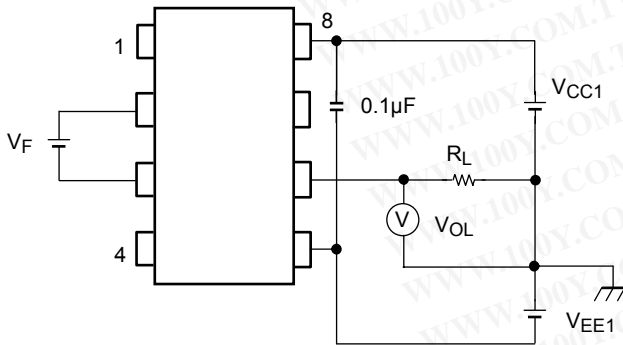
Test Circuit 3: I_{OPH}



Test Circuit 4: V_{OH}

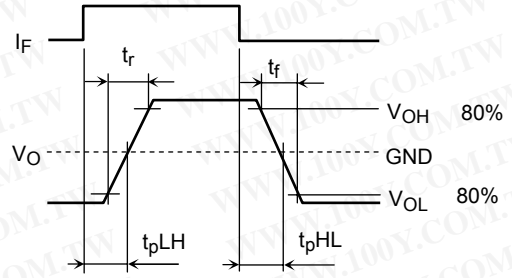
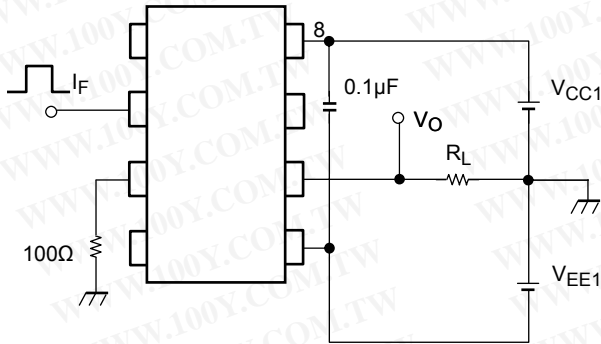


Test Circuit 5: V_{OL}

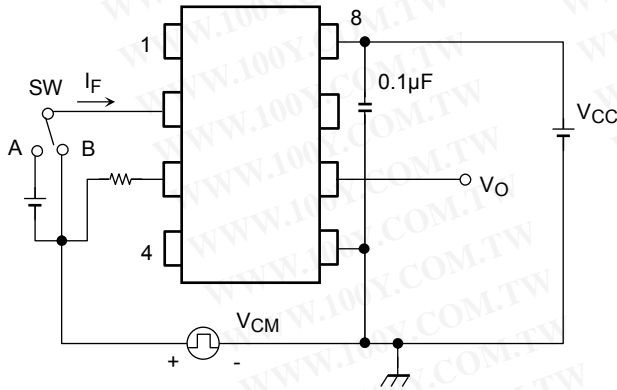


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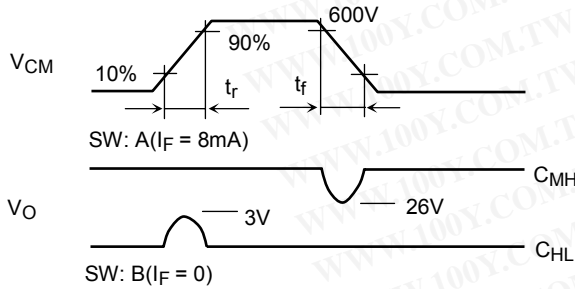
Test Circuit 6: t_{pLH} , t_{pHL} , t_r , t_f



Test Circuit 7: C_{MH} , C_{ML}



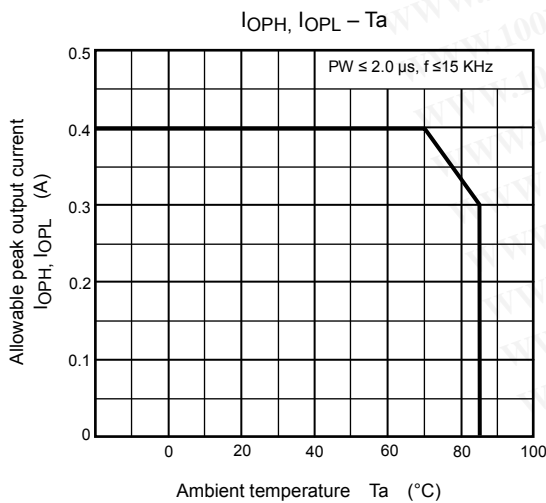
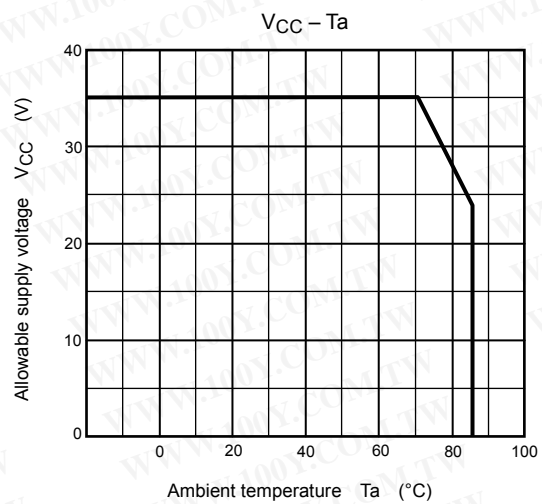
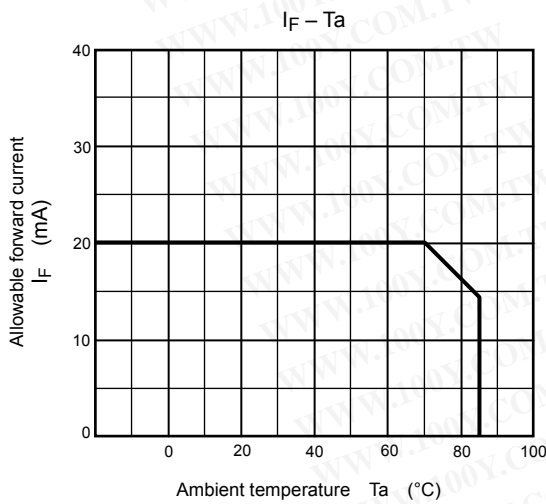
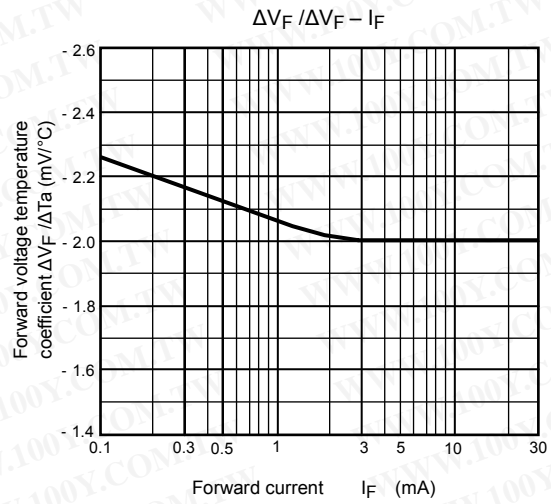
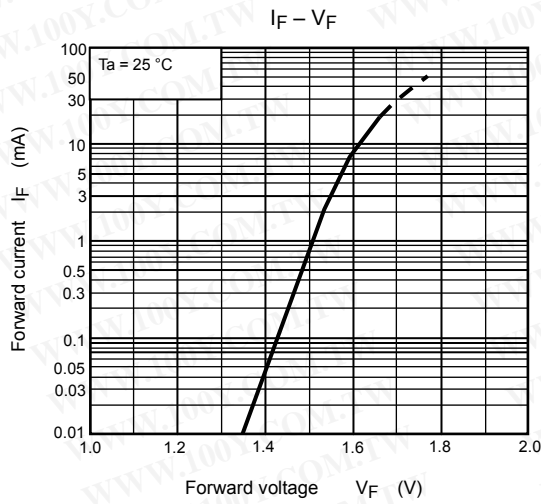
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$$C_{ML} = \frac{480(V)}{t_r(\mu s)}$$

$$C_{MH} = \frac{480(V)}{t_f(\mu s)}$$

C_{ML} (C_{MH}) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.



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